Interface properties and built-in potential profile of a LaCrO₃/SrTiO₃ superlattice determined by standing-wave excited photoemission spectroscopy


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LaCrO₃ (LCO)/SrTiO₃ (STO) heterojunctions are intriguing due to a polar discontinuity along [001], exhibiting two distinct and controllable charged interface structures [(LaO)⁺/(TiO₂)₀] and [(SrO)⁰/(CrO₂)⁻] with induced polarization, and a resulting depth-dependent potential. In this study, we have used soft- and hard-x-ray standing-wave excited photoemission spectroscopy (SW-XPS) to quantitatively determine the elemental depth profile, interface properties, and depth distribution of the polarization-induced built-in potentials. We observe an alternating charged interface configuration: a positively charged (LaO)⁺/(TiO₂)₀ intermediate layer at the LCOtop/STObottom interface and a negatively charged (SrO)⁰/(CrO₂)⁻ intermediate layer at the STOtop/LCObottom interface. Using core-level SW data, we have determined the depth distribution of species, including through the interfaces, and these results are in excellent agreement with scanning transmission electron microscopy and electron energy-loss spectroscopy mapping of local structure and composition. SW-XPS also enabled deconvolution of the LCO and STO contributions to the valence-band (VB) spectra. Using a two-step analytical approach involving first SW-induced core-level binding-energy shifts and then VB modeling, the variation in potential across the complete superlattice is determined in detail. This potential is in excellent agreement with density functional theory models, confirming this method as a generally useful tool for interface studies.

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I. INTRODUCTION

Interfaces between two distinct complex oxide materials offer a wide range of emergent electronic, magnetic, and optical properties that are not found in bulk materials. These include two-dimensional electron gases (2DEGs) in many coupled materials [1], interfacial ferromagnetism in materials that do not exhibit bulk ferromagnetism [2], and interface-induced photocconductivity due to interfacial dipole moments [3,4]. Superlattices (SLs) of these materials offer additional degrees of control and measurement because they comprise many repeating interfaces, thus amplifying interface-specific effects. For example, oxide SLs have produced the first observation of a polar vortex in PbTiO₃/SrTiO₃ (STO) SL [5], and a room-temperature multiferroic exhibiting ferroelectricity, and ferromagnetism in LuFeO₃/LuFe₂O₄ SLs [6]. It has recently been demonstrated by Comes et al. [7] that interfacial engineering can be used to induce a polarization in LaCrO₃ (LCO)/STO SLs. In light of recent studies of the LaFeO₃/STO(001) interface where promising photoconductive and photocatalytic behaviors have been observed [8,9], modulating the electronic structure and band alignment of a material in the form of a SL could be a promising avenue for light capture and conversion applications. To explain the behavior of these materials, accurate experimental determination of the depth-dependent composition, electronic structure, and possible built-in potential gradients at buried interfaces in such SLs is essential. This paper demonstrates that standing-wave excited photoemission can uniquely and nondestructively determine the built-in potential, along with the other properties mentioned above.

While computational modeling at the level of density functional theory (DFT) enables predictions of electronic behavior in these materials, it is significantly more difficult to experimentally determine the depth profiles of composition, electronic structure, and potential profiles in a SL. Traditional approaches for single-interface heterostructures cannot be readily applied to understand the behavior of systems consisting...
of multiple buried interfaces. In the case of a single interface, it is straightforward to measure electronic band alignment between a thin film and the underlying substrate using x-ray photoelectron spectroscopy (XPS) [10,11]. Careful modeling of the XPS data can even allow for determination of surface band bending and potential gradients due to band offsets across an interface [8,12]. When studying a SL, however, one obtains signals from multiple buried interfaces in a single measurement, making modeling exceptionally difficult due to the large number of assumptions that must be made to determine the properties of specific interfaces.

Standing-wave excited x-ray photoelectron spectroscopy (SW-XPS) measurements are a particularly promising way to overcome the challenges associated with SLs because they offer a mean to highlight individual interfaces by selectively tuning the intensity of the electric field with depth in the film [13,14]. This approach was first applied to an oxide SL by Gray et al. in particular for La$_{0.7}$Sr$_{0.3}$MnO$_3$/STO SL to study interfacial magnetic phenomena [15], and has since been used by Nemšák et al. to determine the depth distribution of the 2DEG in GdTiO$_3$/STO SLs [16].

In this work, we use SW-XPS to study the composition profile, band alignment, and built-in potential of an interface-engineered STO/LCO SL. We find that the electrostatic potential varies in both the STO and LCO layers of the SL, indicating that there are distinct induced electric fields in the two oxides. A method of analyzing core-level shifts with SW excitation is used to derive the associated potential gradients in each layer.

II. EXPERIMENT

A. Sample synthesis

The LCO/STO SLs were synthesized by oxide molecular-beam epitaxy on conducting Nb-doped STO(001) substrates using a shuttered growth approach [7]. The Nb-doped STO(001) substrate was etched using boiling deionized water and annealed at 1000 °C for 30 min in an open-air tube furnace to produce a TiO$_2$-terminated surface. Prior to growth of the SL the flux of each element from the effusion cells was calibrated using a quartz crystal oscillator. Pure STO and LCO calibration films were then grown to more precisely adjust the flux of each element by monitoring the oscillations from reflection high-energy electron diffraction during the shuttered growth [17]. After calibration the effusion cells were left hot and the substrates were heated to 600 °C in an electron cyclotron resonance (ECR) oxygen plasma to clean the surface of adventitious carbon. The film was then grown sequentially using one elemental source at a time to produce a SL structure consisting of [5 u LCO/10 u.c. STO]$_{x10}$. By shuttering the individual metal beams, the SL was synthesized to have alternating positively charged (LaO)$^+$/TiO$_2$)$^+$ and negatively charged (SrO)$^0$/CrO$_2^-$ interfaces, terminating with a (CrO$_2^-$) layer at the free surface.

B. Standing-wave excited photoemission

In this method, the SW is created by the interference between incident and reflected x rays, with the incidence angle $\theta_i$ being scanned over the first-order Bragg condition of the SL under study, as given by $\lambda_s = 2d_{ML} \sin \theta_B$. Here $\lambda_s$ is the wavelength of incident photon, $d_{ML}$ is the period of the SL, and $\theta_B$ is the incidence angle for first-order Bragg reflection. The resulting SW electric-field intensity varies sinusoidally with sample depth, with a period for first-order reflection that is very close to $d_{ML}$, which is 56.8 Å for our SL sample, the configuration of which is shown in Fig. 1(a). Scanning the incidence angle over the Bragg condition changes the position of the SW by half a cycle, and it is this variation that provides unique phase sensitive depth resolution that is not possible with other modes of XPS. The vertical movement of the SW through the sample with changing incidence angle will thus enhance or reduce photoemission from different depths, generating what we will call a rocking curve (RC) of intensity that will have sensitivity to the depth distribution of individual elements, as illustrated below. Figure 1(a) shows a schematic view of such a SW measurement for our specific sample configuration, with different parameters and angles defined. A final important point is that the amplitude of the SW modulation is proportional to the square root of the reflectivity ($R$). It is thus useful to maximize $R$ by, for example, tuning the photon energy to be near a strong absorption resonance for one of the elements within the sample [15,16]. Finally, a specially written x-ray optics computer code (Yang x-ray Optics, xyro) is used in analyzing our SW-XPS data [13,14].

SW-XPS measurements were performed at beamline Cassiope of SOLEIL synchrotron, with the angle $\theta_{SR}$ = 45°, as defined in Fig. 1(a), and hard x-ray SW-XPS measurements were performed at beamline Galaxies of SOLEIL synchrotron, with an angle of $\theta_{SR}$ = 90°. The radiation polarization was in the photoemission plane in both cases. The energy resolution of the soft x-ray SW-XPS is 500 meV and that of hard x-ray SW-XPS is 440 meV. X-ray absorption measurements were carried out at Cassiope using total yield and at beamline 6.3.2 of the Advanced Light Source by direct reflectivity.

C. Scanning transmission electron microscopy and electron-energy-loss spectroscopy measurements

Samples were prepared for scanning transmission electron microscopy and electron energy-loss spectroscopy (STEM-EELS) using a FEI Helios NanoLab dual-beam focused ion-beam microscope and a standard lift-out procedure, with initial cuts made at 30 kV and final polishing done at 5 kV/5,5° and 2 kV/6° incidence angle. STEM-HAADF (high-angle annular dark field) images and STEM-EELS maps were collected along the STO [100] zone axis on an aberration-corrected JEOL ARM-200CF microscope operating at 200 kV, with a convergence angle of 27.5 mrad and an EELS collection angle of 82.7 mrad. Spectra were collected with a 1 Å spot size, 1 eVch$^{-1}$ energy dispersion, and a 4× energy binning to improve the signal collection rate. No plural scattering correction was performed since zero loss measurements confirm that the samples are sufficiently thin [t/\lambda \approx 0.5 IMFP (inelastic mean free path)]. The composition maps were processed using principal component analysis to further reduce noise.
FIG. 1. (a) Schematic of the superlattice made up of 10 bilayers of LCO and STO, consisting of 5 unit cells of LCO, 17.6 Å thick, and 10 unit cells of STO, 39.2 Å thick, grown epitaxially on a Nb-doped STO(001) substrate. The two sources of standing-wave structure in the rocking curves are indicated: Bragg reflection from the multilayer with period \(d_{ML}\), and Kiessig fringes associated with the full thickness of the multilayer stack \(D_{ML}\). (b) The x-ray absorption coefficient over the La \(M_5\) edge. (c) The real (delta) and imaginary (beta) parts of the index of refraction, as derived by Kramers-Kronig analysis. To enhance the reflectivity and thus the strength of the standing-wave effect, two photon energies were chosen, below and above the La \(M_5\) absorption maximum. The electric-field strength distribution derived from x-ray optics calculations at these two energies, (d) 829.7 eV and (e) 831.5 eV, as a function of sample depth and incidence angle. Note the significant shift in position between the two energies. The corresponding calculated photoemission yields with depth, (f) and (g), plotted on log10 scales.

III. RESULTS AND DISCUSSION

A. Standing-wave excited photoemission and rocking curves

We conducted two sets of soft x-ray experiments with photon energies just below and just above the La \(M_5\) x-ray absorption maximum at 830.5 eV, as shown in Fig. 1(b). As illustrated in Fig. 1(c), the real (refractive) and imaginary (absorptive) parts of the index of refraction, delta and beta, respectively, of the LCO layer vary dramatically in the proximity of the absorption peak. Two photon energies, 829.7 and 831.5 eV, were chosen to maximize reflectivity at two positions adjacent to the absorption peak, as discussed in more detail in Supplemental Material [18]. Most importantly, this choice of photon energies results in a shift in the SW phase between two measurements, as illustrated in Figs. 1(d) and 1(e), and enlarges the range of sampling depth for the SW-XPS experiments to encompass more or less the first bilayer of the sample. Figures 1(f) and 1(g) also demonstrate more clearly the true sampling depth, with the SW intensities being multiplied by the appropriate inelastic mean free paths for the representative photoelectron peaks (note the logarithmic scale).

In order to shift the SW along the depth direction, spectra were measured as a function of incidence angle between 5.5° and 10° for \(h\nu = 829.7\) eV, between 6° and 10° at 831.5 eV. The first-order Bragg reflection from the multilayer is spanned in all cases. To illustrate the spatial distribution of SW versus incidence angle, the YYRO-derived electric-field intensities as a function of incidence angle and sample depth are shown in Figs. 1(d) and 1(e) for the photon energies of 829.7 and 831.5 eV. In Fig. 1(d), at 829.7 eV, as the incidence angle increases in the angle range of 5.5° to 7°, the maximum of the SW lies near the first interface, which we designate as LCO \(_{top}\)/STO \(_{bottom}\). The maximum then sweeps down to the middle of the first STO layer in the angle range of 7° to 8° and stays there until the end of the angle scan. On the other hand, the movement of the SW in Fig. 1(e) at 831.5 eV shows similar behavior as in Fig. 1(d) but with an overall downward shift of \(\sim 20\) Å, yielding more sensitivity to the second interface, STO \(_{top}\)/LCO \(_{bottom}\). Note that the simulated electric-field intensities are all normalized to the incident beam intensity.

Combining SW results from Figs. 1(d) and 1(e), and the estimated depth sensing in Figs. 1(f) and 1(g) that allows for inelastic scattering, we see that in light of the short IMFPs of the valence electrons excited with soft x rays (\(\sim 18\) Å for STO layer and \(\sim 16\) Å for LCO layer), SW-XPS yields strong sensitivity to the top LCO layer and first interface (LCO \(_{top}\)/STO \(_{bottom}\)). In order to probe more deeply, we have also taken a complementary set of hard x-ray SW data at an energy of 3.5 keV. For this case, the angle scan over the Bragg region is between 1.2° and 2.6°. The mean IMFPs of our hard x-ray data are 50 Å, and roughly equal to \(d_{ML} = 56.8\) Å. This means \(\sim 90\%\) of the photoemission yields are from the top two SL periods, so our data at this energy sample the first two buried interfaces. The corresponding simulation-derived electric-field strength distribution and photoemission yield at this higher energy are also shown in Fig. S2 [18].
FIG. 2. (a) Experimental spectra and fitted components of the strongest core level for each atomic species in the LCO/STO superlattice at a photon energy of 829.7 eV. In several cases in (b) and (c), the intensities used are the sums of blue and green components in (a). Experimental (open circles) and YXRO simulated (solid) rocking curves of representative elemental states at photon energies of (b) 829.7 eV and (c) 831.5 eV. The dashed vertical lines indicate the phase difference of the rocking curves. (d) As in (b) and (c) but for experimental and simulated rocking curves at a photon energy of 3.5 keV. Note that in the case of 3.5 keV, clear Bragg peaks and Kiessig fringes are visible in both experiment and theory.

To first determine the detailed depth-resolved composition of the sample, we have measured the RCs of the most intense core levels for each atomic species in the LCO/STO SL at photon energies of 829.7 eV, 831.5 eV, and 3.5 keV. Figure 2(a) shows the strongest core-level spectra for all atomic species in the LCO/STO SL and their fitted components at $h\nu = 829.7$ eV. Here we see C 1s, O 1s, La 4d, Cr 3p, Sr 3d, and Ti 2p spectra, with their soft-x-ray RCs as derived from peak-fitted intensities shown in Fig. 2(b). The effects of the resonant La excitation are seen in the La 4d and Sr 3d spectra. There are strongly screened final states (green) for the La 4d$^5$ and 4d$^3$ manifolds that are shifted $\sim 3.3$ eV to higher binding energy from the unscreened doublet (blue) [19]. We have used the sum of these two doublets to obtain the RC in Fig. 2(b). Also, a prominent high-binding-energy shoulder in the Sr 3d spectrum is a 4d$^{-1}$5p$^{-1}$4f resonant Auger peak associated with La [20]; its intensity was subtracted in arriving at the Sr 3d RC. In contrast, the spectra of Cr 3p and Ti 2p are relatively simple. The low- and high-binding-energy peaks in Cr 3p result from well-known multiplet splittings involving both magnetic and spin-orbit interactions [12]. Significantly, in the Ti 2p spectrum, there is only a Ti$^{3+}$ component and no evidence of a lower-binding-energy Ti$^{3+}$ shoulder. In addition to the dominant O 1s peak (green) corresponding to oxygen in the SL, a surface-related component (magenta) is present, most likely due to surface OH formation resulting from the exposure to atmosphere in transferring the sample to the measurement chamber [21]; its RC is in fact found to be very similar to that of C 1s, another surface-associated species, so we do not plot it in Figs. 2(b) and 2(c).

Figures 2(b) and 2(c) present the experimental RCs (open circles) and best-fit simulations from our x-ray optical program [13] (curves) of the representative elemental states at photon energies of 829.7 and 831.5 eV. For the C 1s, La 4d, Cr 3p, and Ti 2p spectra in Fig. 2(a), because the blue and green components share the same spatial distribution, the sums of their intensities are plotted as the RCs. In contrast, only the green components are taken into account for O 1s and Sr 3d. A linear background is subtracted from the experimental RCs to compensate the intensity variation of the incident photon resulting from slightly off-axis sample rotation. Note that all the RCs are normalized to a maximum of unity and are offset vertically for readability. The fractional modulation of each RC can thus be read directly from the ordinate scale.

In Figs. 2(b) and 2(c), the RCs of the core levels for the atomic species in the same layer, e.g., La 4d and Cr 3p, as well as Sr 3d and Ti 2p, have almost identical intensity profiles; conversely the RCs corresponding to different layers are completely out of phase, e.g., La 4d and Sr 3d. At the same time, the C 1s RCs exhibit unique profiles owing to their unique location at the surface. The RCs of O 1s follow those of La 4d and Cr 3p since most of the photoemission yield of O 1s comes from the topmost LCO layer when measuring with soft x-ray excitation. The same conclusions are reached by looking at the deeper probing RCs with 3.5 keV excitation in Fig. 2(d), although the O1s RC tends to be rather flat, since averaging over RCs in a few bilayers. Note the generally excellent agreement between experiment and simulation for the RCs at all energies, in which the thicknesses of all layers and the degree of interfacial mixing have been varied over a
number of choices to yield the best fit as judged by $R$ factor, with a number of prior SW photoemission studies suggesting an accuracy of $\sim \pm 2$–3 Å [13,22].

It is noteworthy that the shapes of the two soft x-ray RCs change markedly in going from below [Fig. 2(b)] to above [Fig. 2(c)] the La 3$d$ resonance; thus, the two sets of data are fully complementary. We also find very strong modulations in these soft x-ray experimental RCs of up to 70%, which facilitates measuring and fitting experiment to theory accurately, including the small phase differences between the different RCs, thus finally arriving at the optimal SL structure determination. For example, we find that there are very small phase differences of 0.2° between Sr 3$d$ and Ti 2$p$ RCs and 0.1° between La 4$d$ and Cr 3$p$ RCs at $h\nu = 831.5$ eV, suggesting asymmetric atom distributions among the two constituent elements of the STO and LCO layers. The effect is smaller, but still noticeable, at $h\nu = 829.7$ eV, with reduced magnitude due to its different probing profile, as discussed above. The conclusion of asymmetric interfacial structures, e.g., between the top and bottom of STO, is consistent with the previous STEM study reported by Comes et al. [23].

As noted above, we show in Fig. 2(d) SW-XPS measurements obtained at 3.5 keV. These data probe more deeply and yield information on the top two interfaces as discussed above. Here, we again see excellent agreement between experiment and simulation, and for exactly the same sample structure that we determined with the softer x-ray energies. Moreover, Bragg peaks along with Kiessig fringes are clearly seen in the hard x-ray data. The relative positions and amplitudes of Kiessig fringes with respect to the Bragg peak are very sensitive to thickness gradients in the SL [15,16]. Hence, the agreement between experiment and simulation ensures excellent regularity for the whole SL. The corresponding simulation-derived electric-field strength distribution and photoemission yield maps at 3.5 keV are shown in Fig. S2 [18].

The simulated RCs have been calculated using the YXRO program [13], with appropriate x-ray optical parameters, IMFPs, and various trial sample structures as input. The SL structure was optimized by minimizing the error between all experimental and simulated RCs simultaneously via iteratively adjusting the input SL structure. The SL structures resulting from the best-fit simulations of the soft x-ray data [Figs. 2(a) and 2(b)] and the hard x-ray data [Fig. 2(c)] are found to be the same. Figure 3 shows the optimized SL structure as determined by SW-XPS and compares this structure to that from STEM-EELS maps, which have been obtained from the same sample. In the SW-XPS structure [Fig. 3(a)] we find that there is a 9 Å-thick surface contamination layer (C+O) at the surface. Moreover, from the SW-XPS results, we find around $\sim 2$–3 Å-thick interfaces in this SL, which consist of alternating positively and negatively charged structures: $(\text{LaO})^+/(\text{TiO}_2)^0$ with positive charge (green) at the LCO$_{top}$/STO$_{bottom}$ interface, and $(\text{SrO})^0/(\text{CrO}_2)^-$ with negative charge (yellow) at the STO$_{top}$/LCO$_{bottom}$ interface. This result is consistent with an $A$-cation layer/$B$-cation layer stacking sequence at both kinds of interfaces. The spatial distributions of Sr, Ti, Cr, and La determined by SW-XPS are plotted separately in Fig. 3(b), using the same color scheme as in the STEM-EELS maps in Fig. 3(c). In Fig. 3(b), a spatial offset between the distributions of $A$ and $B$ cations is clearly resolved; the spatial distributions of La and Sr atomic species are offset $\sim 2$ Å from those of Cr and Ti. These results can be directly compared to the STEM-EELS composition map, where agreement regarding the asymmetric nature of the two interfaces is seen. A grayscale high-angle annular dark-field STEM image is shown along with the STEM-EELS composition maps in Fig. 3(c). These images demonstrate an overall excellent quality and regularity of the SL and reveal no apparent structural imperfection. Moreover, from Fig. 3(a), we notice that the thickness of the SW-XPS-derived LCO plus half of the charged interfaces is $\sim 18$ Å. This is about 8% lower than the 19.4 Å expected, based on the bulk LCO lattice constant. However, judging from the STEM-EELS and HAADF images, 5 complete u.c. of LCO are clearly resolved in most of the repeat units and no atomic planes are obviously missing. Therefore, the thickness variation relative to bulk would likely propagate to step edges and have a negligible effect on the physics that we are going to examine in the following. Further information regarding the structure and uniformity of sample, including integrated profiles of STEM-EELS composition maps, HAADF images with various magnification, and reflectivity measurements, can be found in Figs. S3, S4, and S6 [18].

B. SW-derived depth-resolved built-in potential

With a SL structure with alternating positively and negatively charged interfaces, one might ask does the resulting
we are probing with soft x rays, nearly all the intensities or STO components of the SL can be distinguished. Since simultaneously analyzing the valence-band (VB) and layer-states of the Cr \(3d\) on prior DFT calculations, these correspond to the bonding Fig. 4(a) at low angles that we label A, B, and C. Based There are three prominent features in the VB spectra of LCO/STO interface, with the LCO contributing the majority. VB spectra contain contributions from both the LCO and STO layers, a given RC can be represented as a linear combination of RCs from the individual layers [23], and can be written as

\[
I_{VB}(E_b, \theta_x) = \sum_{layer \ j} \rho_j(E_b) \times I_j(\theta_x).
\]

Here \(I_{VB}(E_b, \theta_x)\) is the experimental RC intensity at a binding energy \(E_b\) and x-ray incidence angle \(\theta_x\), \(j = \text{LCO or STO}, \ I_j(\theta_x)\) is the SW RC contribution from a layer \(j\), for which we use Cr \(3p\) for LCO and Ti \(2p\) for STO, and \(\rho_j(E_b)\) are the deconvolution coefficients related directly to the MEWDOS in layer \(j\). The valence-band RCs at each energy step have been fitted to a linear combination of the characteristic RCs by a least-square fitting routine. Finally, the layer-projected MEWDOSs are derived via weighting the angular-integrated valence-band spectra of Figs. 4(a) and 4(b) with the coefficients derived by fitting over the whole binding-energy range.

Figure 4(c) shows the angle-integrated valence-band spectra and the corresponding projected MEWDOSs for the different constituent layers at photon energies of 829.7 and 831.5 eV. The valence-band edges for the projected MEWDOSs are determined by linear extrapolation to zero, as shown schematically by the black dashed lines in Fig. 4(c). Figure 4(d) shows for reference the MEWDOS results from conventional XPS measurements for thick-film LCO and bulk STO (single-crystal substrate). Furthermore, an interface-induced state, as annotated as peak D in the STO MEWDOSs, which is not seen in the bulk STO electronic structure, is revealed by the deconvolution. This is due to a combination of Sr diffusion into STO [29,30], and possibly a slight artifact of the deconvolution procedure. We define the maximum of state \(E\) as the valence-band edge of the projected STO MEWDOSs in order to directly compare it to the valence-band spectra of bulk STO in the following discussion. When the photon energy is switched from 829.7 to 831.5 eV, we find that the projected MEWDOSs of LCO and STO both shift toward lower binding energy: the valence-band edges move from 0.9 to 0.7 eV and from 3.3 to 3.0 eV for LCO and STO, respectively. The fact that the energy levels of the MEWDOS of both constituent layers vary with changes in the SW-XPS depth profile unambiguously reveals that variations in the electrostatic potential are present within both LCO and STO.

We now discuss a method for determining the detailed form of the built-in potential as a function of depth, beginning with analysis of the variation of core-level binding energies as the SW is scanned through the SL. Figures 5(a) and 5(b) show the experimental peak shifts for the major components in the Sr \(3d\) and La \(4d\) core-level spectra versus x-ray incidence angle at photon energies of 829.7 and 831.5 eV, along with simulated results. The components used for analyzing the experimental peak shifts are the Sr \(3d_{3/2}\) feature and the screened feature in the La \(4d_{5/2}\) spectrum, with their positions determined by curve fitting [18]. The experimental variations for the Sr \(3d\) and La \(4d\) peaks have small but reproducible changes in binding energy on the order of 0.1–0.2 eV as the incidence angle is scanned. Moreover, the form of these is quite different for the two x-ray energies, as expected from the different phases and forms of the SW. Note that we focus on the change in potential rather than its absolute value for now, and we

![Figure 4](image-url)
represent the peak positions by their energy separation relative to the average peak position over the angle scan.

We have modeled the spectra of these peaks over the entire incidence angle range and then extracted the angular dependence of their maximum position as the simulated peak shift. Here we assume that the core-level binding energy follows this potential at each depth, tracking perfectly with the VB maximum in that layer, as in the method of Kraut et al. [11], and further that the potential can be described as a linear variation within each layer. Using the accurate depth-dependent photoemission intensity from Figs. 1(f) and 1(g), we have simulated the peak shifts in the La 4d and Sr 3d spectra, representing core levels in LCO and STO. The intensity versus binding energy in a given layer $j$ at depth $z_i$ with an incidence angle $\theta_x$, $I_j(E_b, \theta_x, z_i)$, where $j$ denotes LCO or STO and $i$ is a continuous depth variable within each layer, is described for convenience as a Voigt function with full width at half maximum equal to the estimated experimental energy resolution, $V(E_b - E_{\text{lin}}^{j}(z_i))$. Here $E_{\text{lin}}^{j}(z_i)$ is the linear built-in potential shift of the binding energy at a given depth in layer $j$. The photoemission intensity from depth $z_i$ is the product of the field strength and the inelastic attenuation factor, $|E(z_i, \theta_x)|^2 \exp(-z_i/\Lambda_e \sin \theta_e)$, with $\Lambda_e$ being the incidence angle, $\Lambda_e$ the IMFP, and $\theta_e$ the electron exit angle with respect to the surface, given by $\theta_e = \theta_x + 45^\circ$. Thus, the binding-energy variation as a function of x-ray incidence angle $\theta_x$, $I_{j,\text{max}}(E_b, \theta_x)$, is calculated from the maximum intensity position of the sum, and is described as

$$I_{j,\text{max}}(E_b, \theta_x) = \max \left\{ \sum_{i} I_{j,\text{max}}(E_b, \theta_x, z_i) \right\}$$

$$= \sum_{i} V(E_b - E_{\text{lin}}^{j}(z_i)) |E(z_i, \theta_x)|^2 \exp(-z_i/\Lambda_e \sin \theta_e).$$  \hspace{1cm} (2)

Then, using the accurate depth-dependent photoemission intensity from Figs. 1(f) and 1(g) as the second two factors in the right-hand side of this equation, as well as the assumed linear form of the potential (the first factor) as a trial-and-error input, the best potential gradients were determined by...
least-square fitting, and these result in the smooth curves shown in Figs. 5(a) and 5(b). More details on this simulation method are contained in the discussion of Figs. S8 and S9 [18].

We find generally excellent agreement between experiment and theory in Figs. 5(a) and 5(b), with only Sr 3d showing less variation in theory than in experiment, perhaps due to intermixing with the LCO layer. The potential gradients yielding these fits are shown in Figs. 5(e) and 5(f) and include +1 eV and −0.8 eV changes in binding energy along the depth direction within the LCO and STO layers, respectively.

The energy steps or valence-band offsets at each interface shown in Fig. 5(e) are further determined by the following analysis of the valence-band maxima. Figures 5(c) and 5(d) summarize two different ways of looking at the overall VB spectra at the same two photon energies. The deconvoluted MEWDOS of the STO layer and LCO layer from Fig. 4(c) is one set of curves. The curves denoted “simulation” are based upon inserting the XPS bulk reference spectra from Fig. 4(d), $I_{V_B,j}^XPS(E_b)$, with $j = \text{LCO}$ or STO, into a sum over the built-in potential similar to that shown in Eq. (2),

$$I_{V_B,j}^XPS(E_b) = \sum_{\theta_e, z_i} \sum_{z_i} \left| I_{V_B,j}^{\text{XPS}}(E_b - E_b^0(z_i)) \left| E(z_i, \theta_e) \right| \right|^2 \times \exp \left( -z_i/\Lambda_e \sin \theta_e \right) \right.$$  

(3)

with the total potential $E_b^0(z_i)$ shown in Fig. 5(e), including potential gradients within constituent layers and steps at the polar interfaces due to band offsets, with the steps being varied to fit the VBM shifts discussed above. A further elaboration of this simulation process can be found in Fig. S9 and its discussion.

By combining the derivation of the slopes of electrostatic potential within each layer and the magnitude of valence-band offsets at two kinds of charged interface, we finally determine the absolute potential value with respect to the VB maxima, annotated as the SW-XPS-derived profile in Figs. 5(e) and 5(f). We note that this procedure yields a uniquely precise specification of the potential variations along the depth direction. The VB edge of the LCO layer shifts toward higher binding energy by 1 eV within 5 u.c. of LCO, which results in a change in binding energy from 0.2 eV at the STO$_\text{bottom}$/LCO$_\text{bottom}$ (negatively charged) interface, or the surface for the topmost LCO, to 1.2 eV at the LCO$_\text{top}$/STO$_\text{bottom}$ (positively charged) interface. At the same time, the VB edge of the STO layer shifts to a lower binding energy by 0.8 eV within 10 u.c. STO, which is equivalent to a change in binding energy from 3.1 eV at the LCO$_\text{top}$/STO$_\text{bottom}$ interface (positively charged) to 2.3 eV at the STO$_\text{top}$/LCO$_\text{bottom}$ Interface (negatively charged). This result indicates clear agreement between the qualitative expectation of the charged interface configuration and the signs of the potential gradients: higher (lower) binding energy for valence electrons at the positively (negatively) charged interfaces.

C. Density-functional theory

We have corroborated these results using DFT simulations with the PBEsol density functional [31], as implemented in the VASP code [32,33] with an adjustable $U_{\text{eff}}$ parameter for $d$-$d$ correlation in both layers and these results are found to agree excellently with the experimental results as to both slopes and offsets at the interfaces, as shown by the black curves in Figs. 5(e) and 5(f). In Fig. 5(e), the $U_{\text{eff}}$ values in LCO (8 eV) and STO (3 eV) were chosen to yield the correct bulk band gaps. We note that while $U_{\text{eff}}$(Cr) = 3.0 eV and $U_{\text{eff}}$(Ti) = 8.0 eV produces a correct trend and that theory agrees with experiment to within about 0.5 eV within the layers, the best agreement between the calculated and the experimental VB maximum profiles is found for $U_{\text{eff}}$(Cr) = 1.5 eV and $U_{\text{eff}}$(Ti) = 4.0 eV, as shown in Fig. 5(f). This may indicate that the larger values of $U_{\text{eff}}$ introduce artificial electronic structure effects that exaggerate the internal field, or that the interfaces contain defects that partially offset the correlation effects on the field in the film. To see the trend of how the VB maximum profiles vary with the values of $U_{\text{eff}}$, a further discussion of these theoretical calculations with different choices can be found in Fig. S10 [18].

IV. CONCLUSION

In summary, standing-wave excited soft- and hard x-ray photoemission measurements have been applied to a LaCrO$_3$/SrTiO$_3$ SL that is expected to contain charged interfaces, in order to extract the depth-resolved atomic and electronic structure, and for the built-in potential. In the soft-x-ray measurements, two photon energies above and below the La M$_5$ absorption edge were carefully chosen. These values lead to very large reflectivities and thus RC modulations of up to 70% and, because of the different phases of the SW with depth at the two energies, a sampling range which covers nearly the entire top LCO/STO bilayer, including top and bottom interfaces. In addition, complementary hard x-ray measurements were conducted to increase the probing depth. In all of these experiments, the Bragg peak is clearly resolved in the RCs, and for the higher-energy x ray, also Kiessig fringes. The same depth distributions for each atomic species are derived from RC analysis of the soft- and hard x-ray regimes, and these distributions are in excellent agreement with STEM-EELS composition maps. Both sets of RC data, along with the STEM-EELS maps, are consistent with alternating charged interfaces: a (LaO)$_{+}$(TiO$_2$)$_{0}$ intermediate layer at the LCO$_\text{top}$/STO$_\text{bottom}$ (negatively charged) interface and a (SrO)$_{0}$/(CrO$_2$)$_{0}$ intermediate layer at the STO$_\text{top}$/LCO$_\text{bottom}$ interface. Furthermore, we have deconvoluted the valence-band spectra into the MEWDOS of STO and LCO layers by analyzing the layer-specific, core-level RCs together with valence-band RCs. Further sequential analysis of core-level shifts as the SW is scanned vertically with angle, and the deconvoluted VB spectra compared to reference simulations, has permitted determining in unique detail the variation of the built-in potential with depth, including the band offsets at the polar interfaces. This overall potential is in excellent agreement with DFT, confirming the method. As a final comment, we believe that the SW methods we have introduced here should have wide applicability in the study of not only oxide interfaces and their built-in potentials, but also many other types of heterostructures, including, e.g., the electrochemical double layer, for which similar core-level shifts with SW excitation have been observed recently, but not yet analyzed with the method introduced here [34].
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